# JK Flip Flop

The MC10EP35 is a higher speed/low voltage version of the EL35 JK flip flop. The J/K data enters the master portion of the flip flop when the clock is LOW and is transferred to the slave, and thus the outputs, upon a positive transition of the clock. The reset pin is asynchronous and is activated with a logic HIGH.

- 300ps Propagation Delay
- High Bandwidth to 3 GHz Typical
- High Bandwidth Output Transistors
- PECL mode: 3.0V to 5.5V  $V_{CC}$  with  $V_{EE} = 0V$
- ECL mode:  $0V V_{CC}$  with  $V_{EE} = -3.0V$  to -5.5V
- 75kΩ Internal Input Pulldown Resistors
- Q Output will default LOW with inputs open or at VEE
- ESD Protection: >4KV HBM, >200V MM
- Moisture Sensitivity Level 1, Indefinite Time Out of Drypack.
   For Additional Information, See Application Note AND8003/D
- Flammability Rating: UL-94 code V-0 @ 1/8", Oxygen Index 28 to 34
- Transistor Count = 77 devices

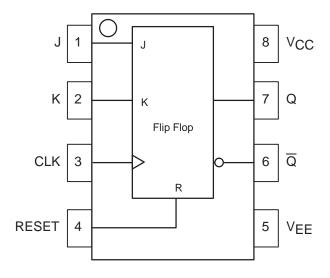


Figure 1. 8-Lead Pinout (Top View) and Logic Diagram



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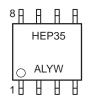
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SO-8 D SUFFIX CASE 751

#### **MARKING DIAGRAM**



A = Assembly Location

L = Wafer Lot Y = Year W = Work Week

\*For additional information, see Application Note AND8002/D

PIN DESCRIPTION							
PIN FUNCTION							
CLK	ECL Clock Inputs						
J, K	ECL Signal Inputs						
RESET	ECL Asynchronous Reset						
Q, Q	ECL Data Outputs						

	TRUTH TABLE									
J	K	RESET	CLK	Qn+1						
L L H X	LHLX	H	Z Z Z Z X	Qn L H Qn L						

Z = LOW to HIGH Transition

### **ORDERING INFORMATION**

Device	Package	Shipping
MC10EP35D	SOIC	98 Units/Rail
MC10EP35DR2	SOIC	2500 Tape & Reel

#### **MAXIMUM RATINGS\***

Symbol	Parameter	Value	Unit	
V <sub>EE</sub>	Power Supply (V <sub>CC</sub> = 0V)		-6.0 to 0	VDC
Vcc	Power Supply (VEE = 0V)		6.0 to 0	VDC
V <sub>I</sub>	Input Voltage (V <sub>CC</sub> = 0V, V <sub>I</sub> not more negative than	n V <sub>EE</sub> )	-6.0 to 0	VDC
VI	Input Voltage (VEE = 0V, VI not more positive than	6.0 to 0	VDC	
lout	Output Current	Continuous Surge	50 100	mA
TA	Operating Temperature Range		-40 to +85	°C
T <sub>stg</sub>	Storage Temperature		-65 to +150	°C
θЈА	Thermal Resistance (Junction-to-Ambient)	Still Air 500lfpm	190 130	°C/W
θJC	Thermal Resistance (Junction-to-Case)		41 to 44 ± 5%	°C/W
T <sub>sol</sub>	Solder Temperature (<2 to 3 Seconds: 245°C desire	ed)	265	°C

<sup>\*</sup> Maximum Ratings are those values beyond which damage to the device may occur.

# DC CHARACTERISTICS, ECL/LVECL ( $V_{CC} = 0V$ ; $V_{EE} = -5.5V$ to -3.0V) (Note 3.)

			–40°C			25°C			85°C		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
IEE	Power Supply Current (Note 1.)	30	40	50	30	40	50	30	40	50	mA
VOH	Output HIGH Voltage (Note 2.)	-1135	-1060	-885	-1070	-945	-820	-1010	-885	-760	mV
VOL	Output LOW Voltage (Note 2.)	-1935	-1810	-1685	-1870	-1745	-1620	-1810	-1685	-1560	mV
VIH	Input HIGH Voltage Single Ended	-1210		-885	-1145		-820	-1085		-760	mV
V <sub>IL</sub>	Input LOW Voltage Single Ended	-1935		-1610	-1870		-1545	-1810		-1485	mV
lН	Input HIGH Current			150			150			150	μΑ
Ι <sub>Ι</sub>	Input LOW Current	0.5			0.5			0.5			μΑ

NOTE: 10EP circuits are designed to meet the DC specifications shown in the above table after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse airflow greater than 500lfpm is maintained.

1. V<sub>CC</sub> = 0V, V<sub>EE</sub> = V<sub>EEmin</sub> to V<sub>EEmax</sub>, all other pins floating.

2. All loading with 50 ohms to V<sub>CC</sub>-2.0 volts.

3. Input and output parameters vary 1:1 with V<sub>CC</sub>.

# DC CHARACTERISTICS, LVPECL ( $V_{CC} = 3.3V \pm 0.3V$ , $V_{EE} = 0V$ ) (Note 6.)

			–40°C			25°C			85°C		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
IEE	Power Supply Current (Note 4.)	30	40	50	30	40	50	30	40	50	mA
VOH	Output HIGH Voltage (Note 5.)	2165	2240	2415	2230	2355	2480	2290	2415	2540	mV
VOL	Output LOW Voltage (Note 5.)	1365	1490	1615	1430	1555	1680	1490	1615	1740	mV
VIH	Input HIGH Voltage Single Ended	2090		2415	2155		2480	2215		2540	mV
VIL	Input LOW Voltage Single Ended	1365		1690	1430		1755	1490		1815	mV
lн	Input HIGH Current			150			150			150	μΑ
I <sub>IL</sub>	Input LOW Current	0.5			0.5			0.5			μΑ

NOTE: 10EP circuits are designed to meet the DC specifications shown in the above table after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse airflow greater than 500lfpm is maintained.

- 4.  $V_{CC} = 3.3V$ ,  $V_{EE} = 0V$ , all other pins floating.
- 5. All loading with 50 ohms to V<sub>CC</sub>-2.0 volts.
- 6. Input and output parameters vary 1:1 with VCC.

## DC CHARACTERISTICS, PECL ( $V_{CC} = 5.0V \pm 0.5V$ , $V_{EE} = 0V$ ) (Note 9.)

			–40°C			25°C			85°C		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
IEE	Power Supply Current (Note 7.)	30	40	50	30	40	50	30	40	50	mA
Vон	Output HIGH Voltage (Note 8.)	3865	3940	4115	3930	4055	4180	3990	4115	4240	mV
VOL	Output LOW Voltage (Note 8.)	3065	3190	3315	3130	3255	3380	3190	3315	3440	mV
VIH	Input HIGH Voltage Single Ended	3790		4115	3855		4180	3915		4240	mV
VIL	Input LOW Voltage Single Ended	3065		3390	3130		3455	3190		3515	mV
lН	Input HIGH Current			150			150			150	μΑ
I <sub>IL</sub>	Input LOW Current	0.5			0.5			0.5			μΑ

NOTE: 10EP circuits are designed to meet the DC specifications shown in the above table after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse airflow greater than 500lfpm is maintained.

- 7.  $V_{CC} = 5.0V$ ,  $V_{EE} = 0V$ , all other pins floating.
- 8. All loading with 50 ohms to  $V_{CC}$ -2.0 volts.
- 9. Input and output parameters vary 1:1 with V<sub>CC</sub>.

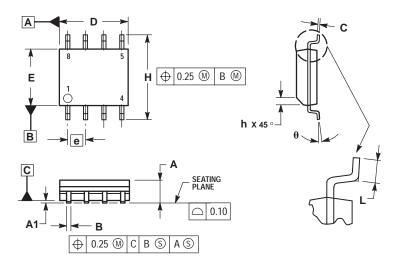
AC CHARACTERISTICS ( $V_{CC} = 0V$ ;  $V_{EE} = -3.0V$  to -5.5V) or ( $V_{CC} = 3.0V$  to 5.5V;  $V_{EE} = 0V$ )

			–40°C			25°C			85°C		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
f <sub>max</sub>	Maximum Toggle Frequency (Note 10.)		3.0			3.0			3.0		GHz
tPLH, tPHL	Propagation Delay to Output Diff. R, CLK->Q, $\overline{Q}$	150	300	450	170	320	470	180	330	480	ps
<sup>t</sup> RR	Set/Reset Recovery		TBD			TBD			TBD		ps
ts tH	Setup Time Hold Time	150 200	0 100		150 200	0 100		150 200	0 100		ps
<sup>t</sup> SKEW	Duty Cycle Skew (Note 11.) Skew Part–to–Part		TBD TBD			TBD TBD			TBD TBD		ps
tpW	Minimum Pulse Width CLK, RESET		400			400			400		ps
<sup>t</sup> JITTER	Cycle-to-Cycle Jitter		TBD			TBD			TBD		ps
t <sub>r</sub> t <sub>f</sub>	Output Rise/Fall Times (20% – 80%) Q, $\overline{\mathbb{Q}}$	50	110	180	60	120	200	70	140	220	ps

<sup>10.</sup> F<sub>max</sub> guaranteed for functionality only. V<sub>OL</sub> and V<sub>OH</sub> levels are guaranteed at DC only.
11. Skew is measured between outputs under identical transitions. Duty cycle skew is defined only for differential operation when the delays are measured from the cross point of the inputs to the cross point of the outputs.

# **PACKAGE DIMENSIONS**

### SO-8 **D SUFFIX** PLASTIC SOIC PACKAGE CASE 751-06 ISSUE T



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
  2. DIMENSIONS ARE IN MILLIMETER.
  3. DIMENSION D AND E DO NOT INCLUDE MOLD PROTRUSION.
  4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
  5. DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 TOTAL IN EXCESS OF THE B DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS									
DIM	MIN	MAX								
Α	1.35	1.75								
A1	0.10	0.25								
В	0.35	0.49								
С	0.19	0.25								
D	4.80	5.00								
Ε	3.80	4.00								
е	1.27	BSC								
Н	5.80	6.20								
h	0.25	0.50								
L	0.40	1.25								
θ	0 °	7 °								

# **Notes**

# **Notes**

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